



# STPS30170C

## HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

Table 1: Main Product Characteristics

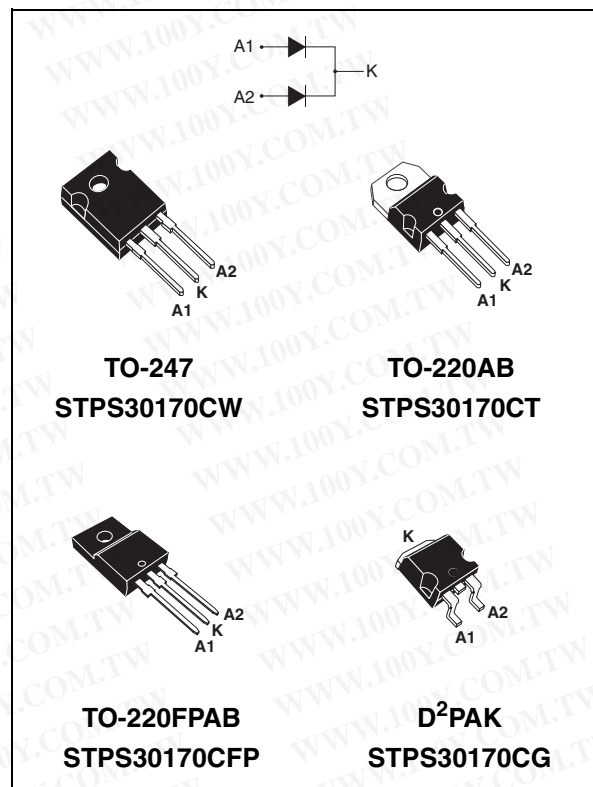
$I_{F(AV)}$	2 x 15 A
$V_{RRM}$	170 V
$T_j$	175 °C
$V_F(max)$	0.75 V

### FEATURES AND BENEFITS

- High junction temperature capability
- Low leakage current
- Good trade off between leakage current and forward voltage drop
- Insulated package: TO-220FPAB  
Insulating voltage: 2000 V DC  
Capacitance: 45 pF
- Avalanche specification

### DESCRIPTION

Dual center tab Schottky rectifier suited for High Frequency Switch Mode Power Supply.



勝特力材料 886-3-5753170  
勝特力电子(上海) 86-21-34970699  
勝特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

Table 2: Order Codes

Part Numbers	Marking
STPS30170CW	STPS30170CW
STPS30170CT	STPS30170CT
STPS30170CFP	STPS30170CFP
STPS30170CG	STPS30170CG
STPS30170CG-TR	STPS30170CG

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**Table 3: Absolute Ratings** (limiting values, per diode)

Symbol	Parameter			Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage			170	V
$I_{F(RMS)}$	RMS forward current			30	A
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO-220FPAB	$T_c = 120\text{ }^\circ\text{C}$	Per diode	A
		TO-220AB / D <sup>2</sup> PAK	$T_c = 155\text{ }^\circ\text{C}$	Per device	
		TO-247			
$I_{FSM}$	Surge non repetitive forward current		$t_p = 10\text{ms}$ sinusoidal	220	A
$P_{ARM}$	Repetitive peak avalanche power		$t_p = 1\mu\text{s}$ $T_j = 25\text{ }^\circ\text{C}$	10500	W
$T_{stg}$	Storage temperature range			-65 to + 175	$^\circ\text{C}$
$T_j$	Maximum operating junction temperature *			175	$^\circ\text{C}$
$dV/dt$	Critical rate of rise of reverse voltage			10000	V/ $\mu\text{s}$

\*:  $\frac{dP_{tot}}{dT_j} > \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

**Table 4: Thermal Parameters**

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220FPAB	Per diode	4	$^\circ\text{C/W}$
			Total	3.3	
		TO-220AB / D <sup>2</sup> PAK	Per diode	1.6	
			Total	0.85	
		TO-247	Per diode	1.5	
			Total	0.8	
$R_{th(c)}$		TO-220FPAB	Coupling	2.6	$^\circ\text{C/W}$
		TO-220AB / D <sup>2</sup> PAK	Coupling	0.3	
		TO-247	Coupling	0.3	

When the diodes 1 and 2 are used simultaneously:  
 $\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$

**Table 5: Static Electrical Characteristics** (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ	Max.	Unit
$I_R$ *	Reverse leakage current	$T_j = 25\text{ }^\circ\text{C}$	$V_R = V_{RRM}$			20	$\mu\text{A}$
		$T_j = 125\text{ }^\circ\text{C}$			5	20	mA
$V_F$ **	Forward voltage drop	$T_j = 25\text{ }^\circ\text{C}$	$I_F = 15\text{ A}$			0.92	V
		$T_j = 125\text{ }^\circ\text{C}$			0.69	0.75	
		$T_j = 25\text{ }^\circ\text{C}$	$I_F = 30\text{ A}$			1	
		$T_j = 125\text{ }^\circ\text{C}$			0.80	0.86	

Pulse test: \*  $t_p = 5\text{ ms}$ ,  $\delta < 2\%$   
 \*\*  $t_p = 380\text{ } \mu\text{s}$ ,  $\delta < 2\%$

To evaluate the conduction losses use the following equation:  $P = 0.64 \times I_{F(AV)} + 0.0073 I_{F(RMS)}^2$



Figure 1: Average forward power dissipation versus average forward current (per diode)

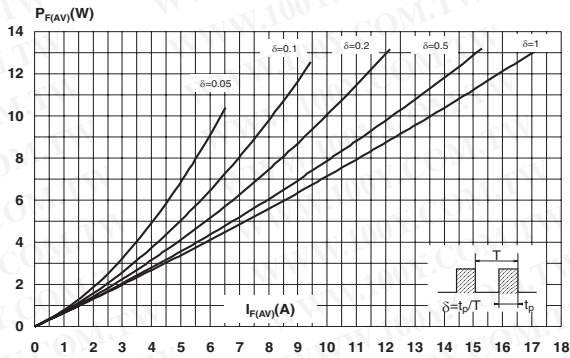


Figure 2: Average forward current versus ambient temperature ( $\delta = 0.5$ , per diode)

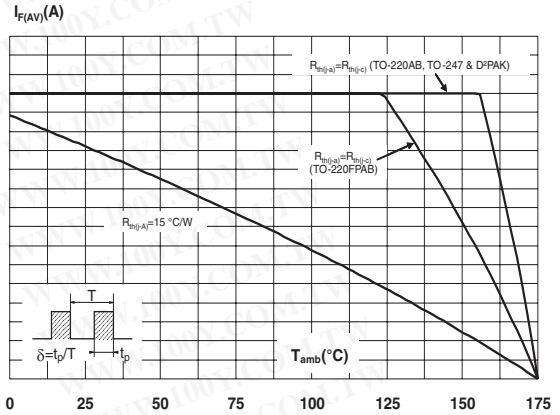


Figure 3: Normalized avalanche power derating versus pulse duration

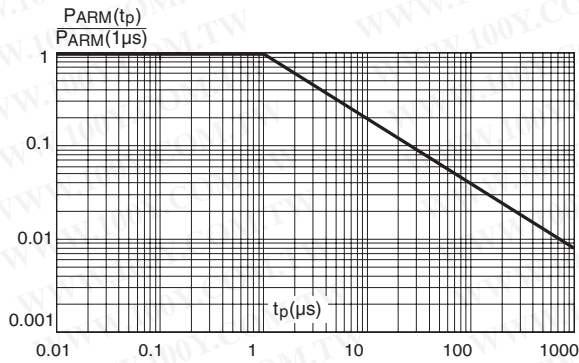


Figure 4: Normalized avalanche power derating versus junction temperature

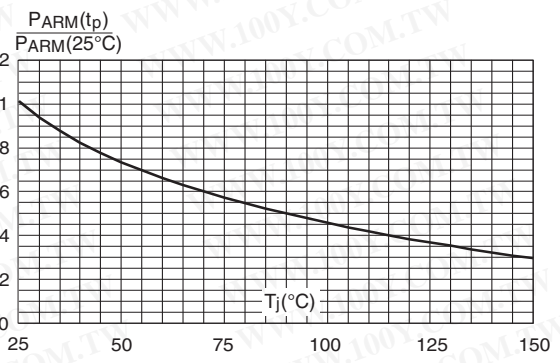


Figure 5: Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220AB, TO-247, D<sup>2</sup>PAK)

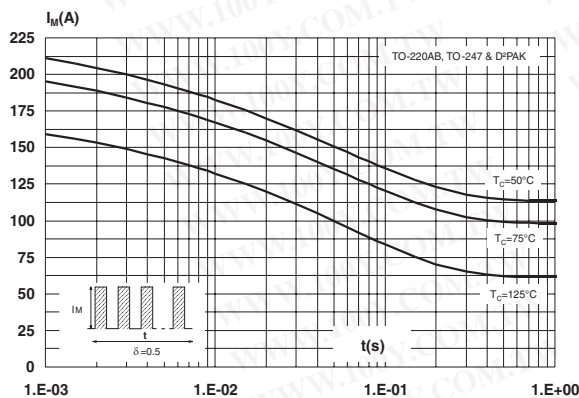
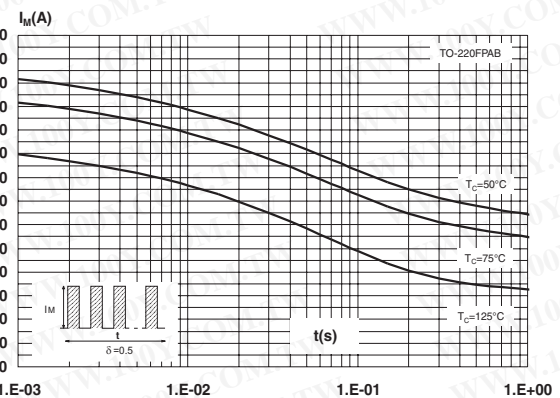


Figure 6: Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220FPAB)



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Figure 7: Relative variation of thermal impedance junction to case versus pulse duration (per diode) (TO-220AB, TO-247, D<sup>2</sup>PAK)

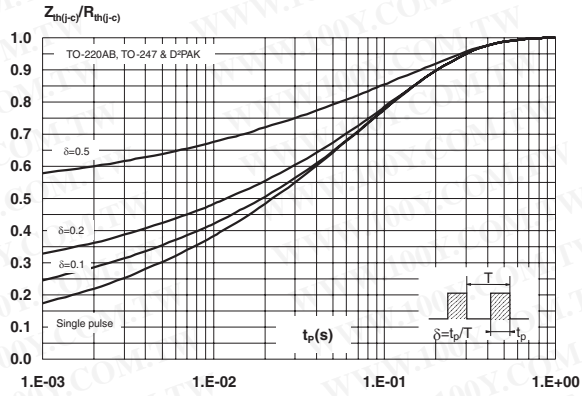


Figure 8: Relative variation of thermal impedance junction to case versus pulse duration (per diode) (TO-220FPAB)

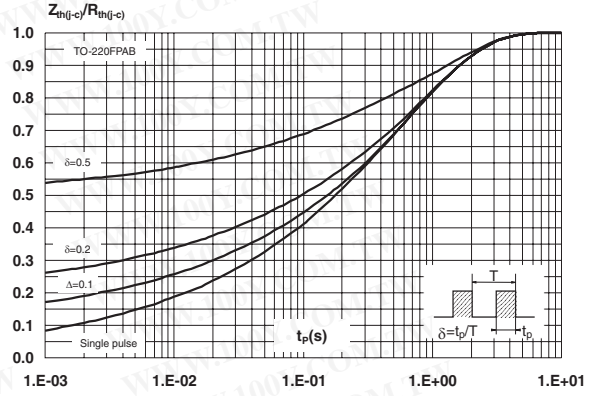


Figure 9: Reverse leakage current versus reverse voltage applied (typical values, per diode)

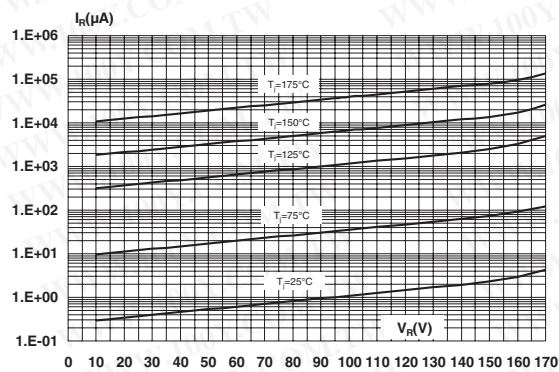


Figure 10: Junction capacitance versus reverse voltage applied (typical values, per diode)

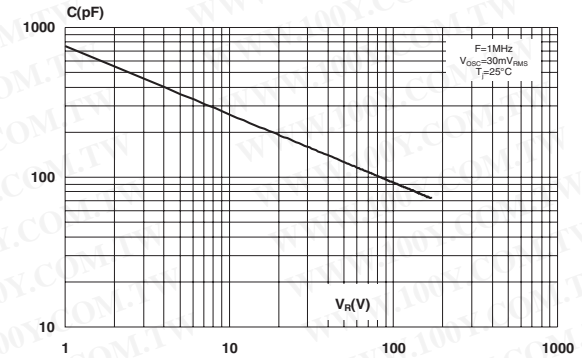


Figure 11: Forward voltage drop versus forward current (maximum values, per diode, low level)

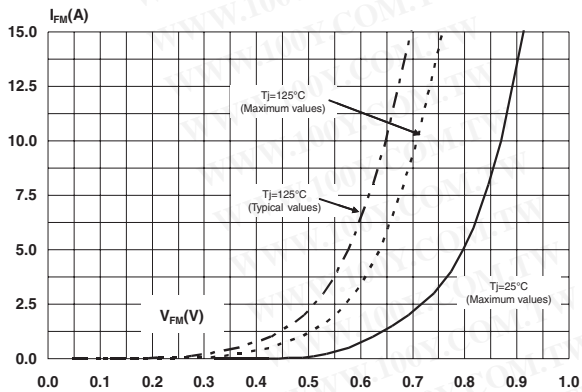


Figure 12: Forward voltage drop versus forward current (maximum values, per diode, high level)

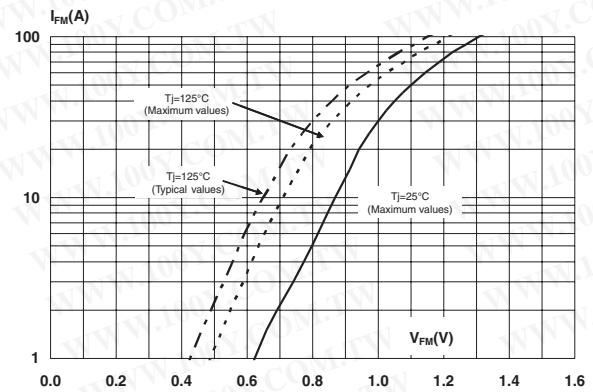


Figure 13: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board, copper thickness: 35 μm) (D<sup>2</sup>PAK)

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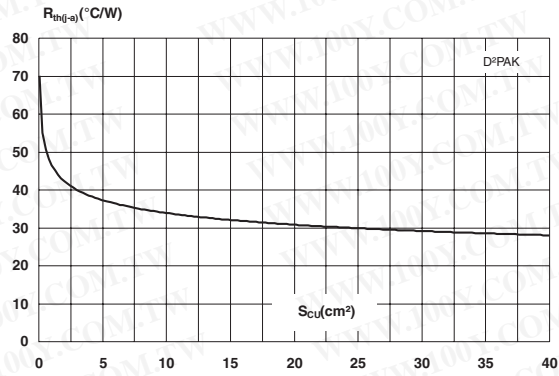


Figure 14: TO-247 Package Mechanical Data

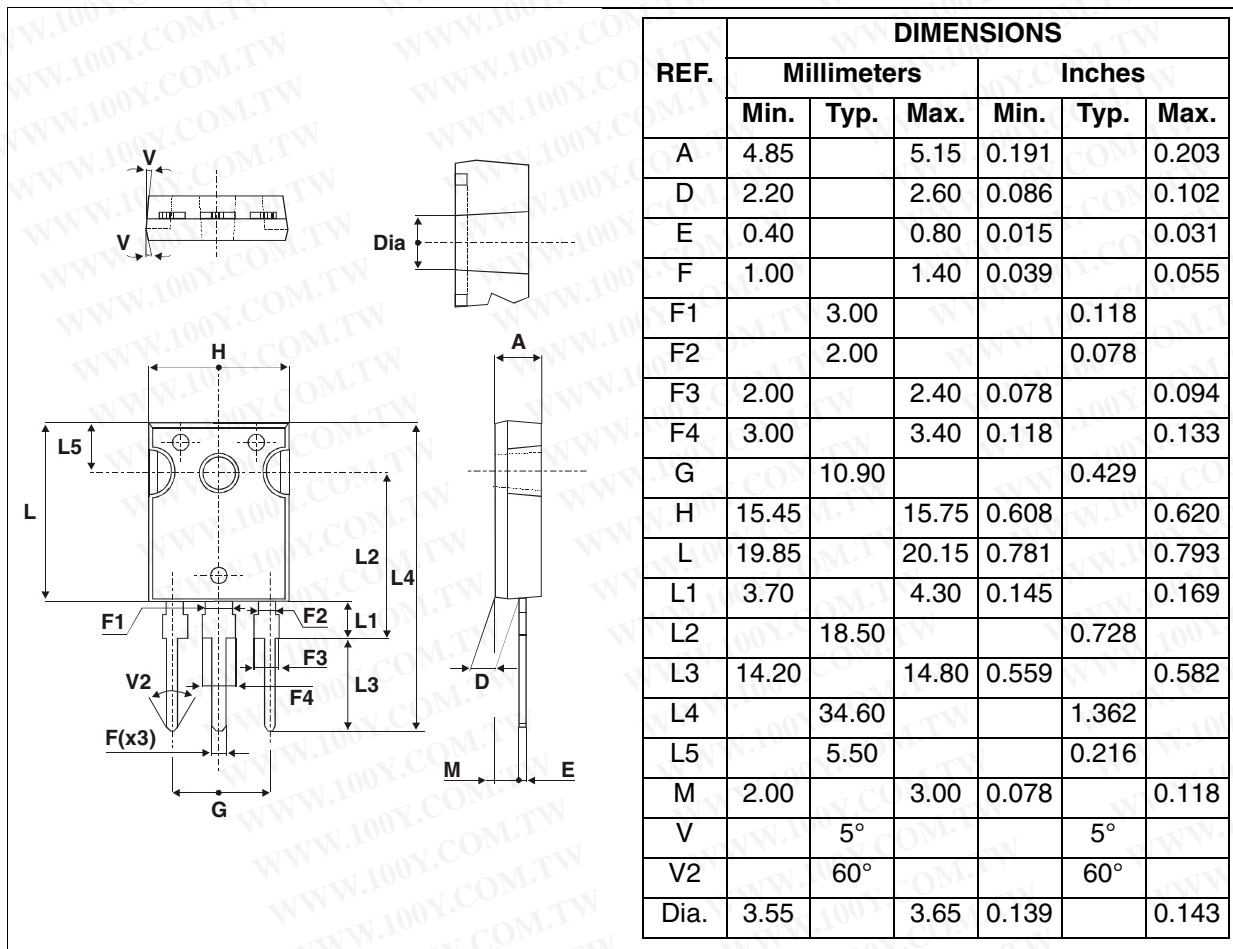


Figure 15: D<sup>2</sup>PAK Package Mechanical Data

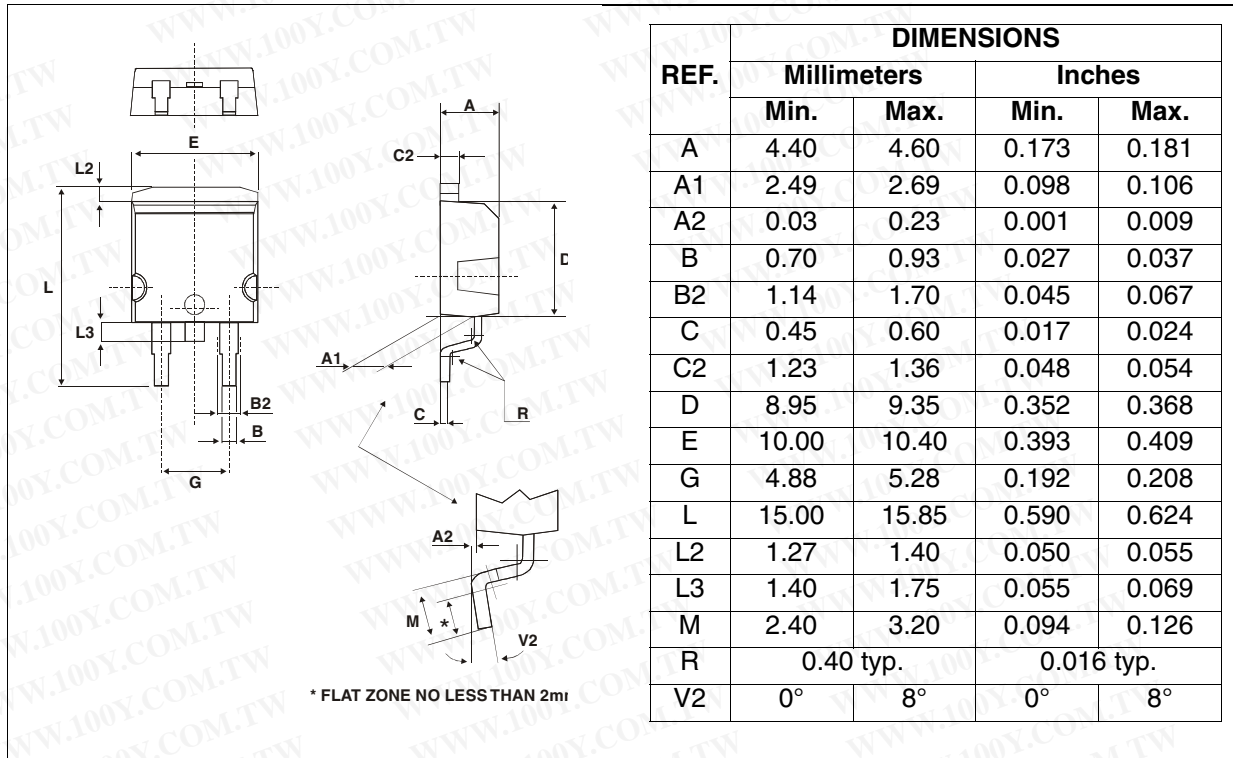
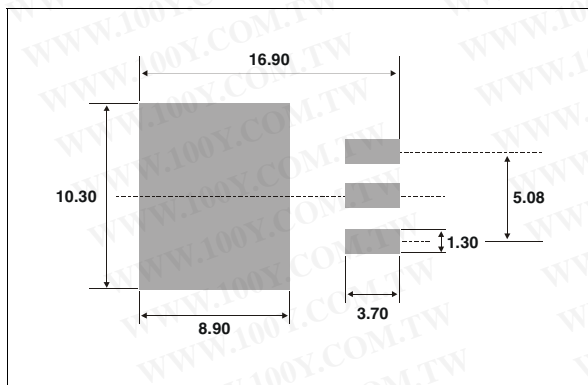
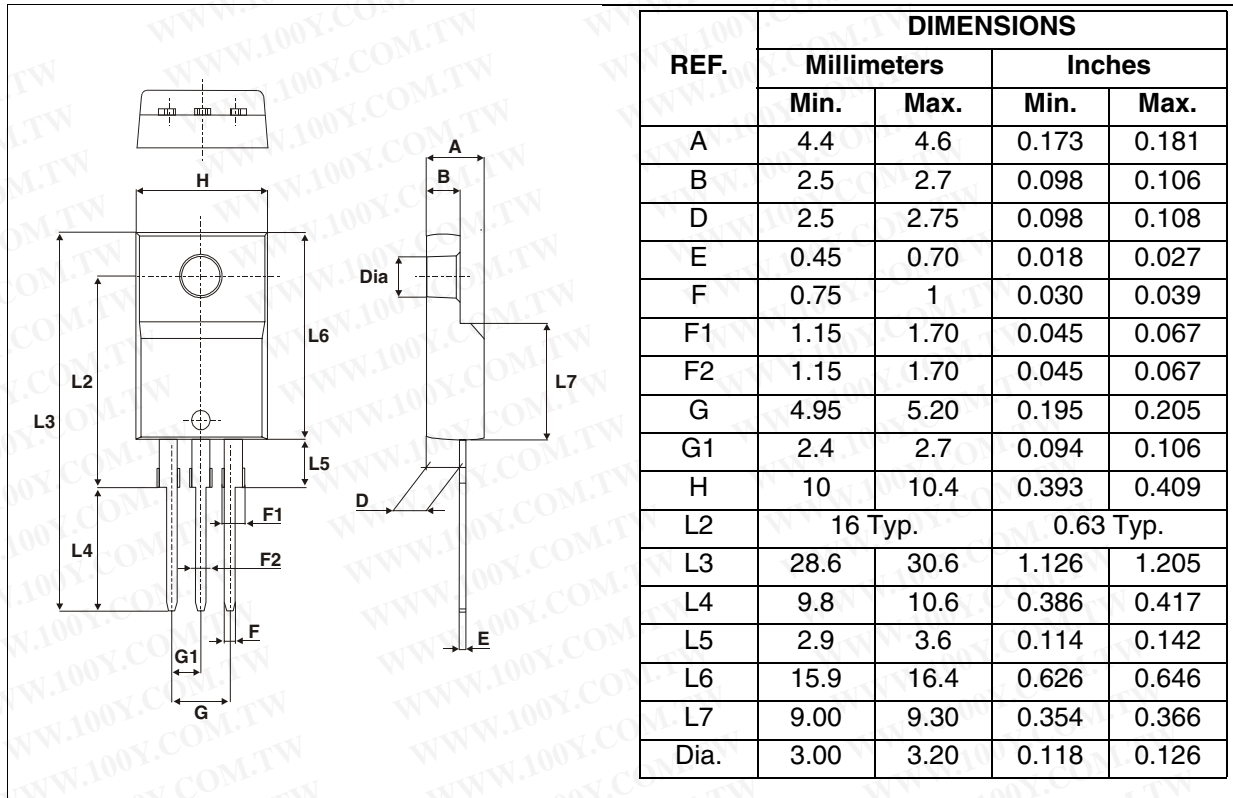


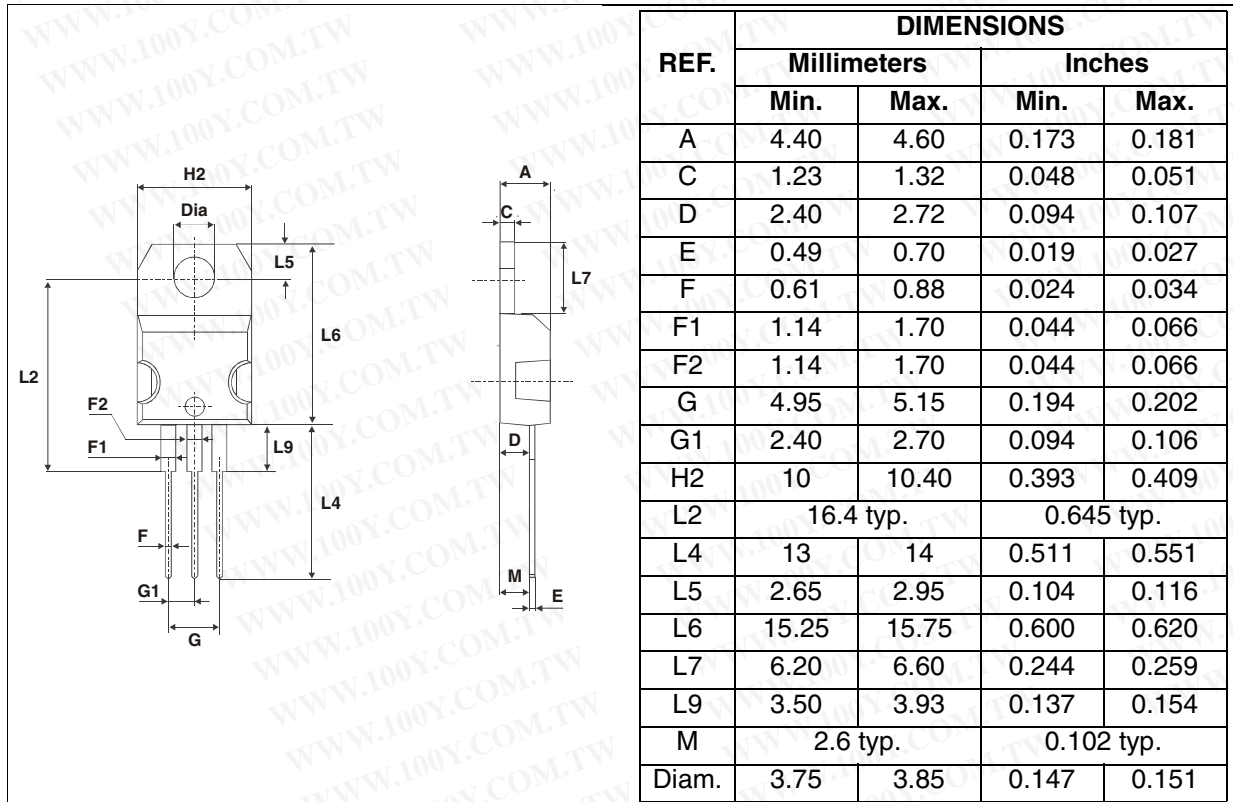
Figure 16: Foot Print Dimensions (in millimeters)



**Figure 17: TO-220FPAB Package Mechanical Data**



**Figure 18: TO-220AB Package Mechanical Data**



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In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).

**Table 6: Ordering Information**

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS30170CW	STPS30170CW	TO-247	4.40 g	30	Tube
STPS30170CT	STPS30170CT	TO-220AB	2 g	50	Tube
STPS30170CFP	STPS30170CFP	TO-220FPAB	1.9 g	50	Tube
STPS30170CG	STPS30170CG	D <sup>2</sup> PAK	1.48 g	50	Tube
STPS30170CG-TR	STPS30170CG			1000	Tape & reel

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- TO-220 - Recommended torque value: 0.55 Nm, Maximum torque value: 0.7 Nm.
- TO-247 - Recommended torque value: 0.8 Nm, Maximum torque value: 1.0 Nm.

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**Table 7: Revision History**

Date	Revision	Description of Changes
16-Sep-2005	1	First issue.



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